

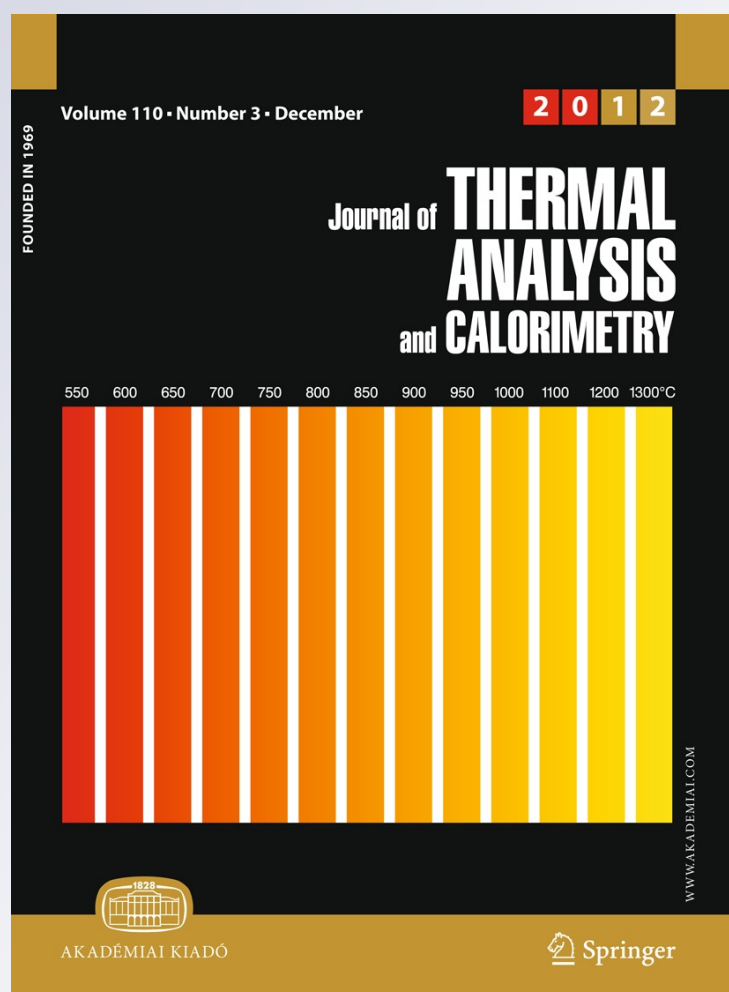
Host-sensitized phosphorescence of Mn^{4+} , Eu^{3+} , and Yb^{3+} in $MgAl_2Si_2O_8$

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Host-sensitized phosphorescence of Mn^{4+} , Eu^{3+} , and Yb^{3+} in $\text{MgAl}_2\text{Si}_2\text{O}_8$

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Abstract Mn^{4+} doped and Eu^{3+} , Yb^{3+} co-doped $\text{MgAl}_2\text{Si}_2\text{O}_8$ -based phosphors were prepared by conventional solid state reaction at 1,300 °C. They were characterized by thermogravimetry, differential thermal analysis, X-ray powder diffraction, photoluminescence, and scanning electron microscopy. The luminescence mechanism of the phosphors, which showed broad red emission bands in the range of 600–715 nm and had a different maximum intensity when activated by UV illumination, was discussed. Such a red emission can be attributed to the intrinsic ${}^2E \rightarrow {}^4A_2$ transitions of Mn^{4+} .

Keywords Mn^{4+} · Eu^{3+} · Yb^{3+} · $\text{MgAl}_2\text{Si}_2\text{O}_8$ phosphors · Aluminosilicates

Introduction

Luminescent materials with long afterglow are kinds of energy storage materials that can absorb both UV and visible light from the sun and gradually release this energy in the dark at a certain wavelength. These kinds of long lasting phosphors have been widely studied by many researchers [1–3].

Silicates therefore are suitable hosts for phosphors because of their high physical and chemical stability. The

luminescence of rare-earth ions in the silicate host has been studied for a long time. In recent years, silicate phosphors have been reported by researchers [4–13].

In this article, $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Eu^{3+} , and $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Yb^{3+} -based phosphors were synthesized by solid state reaction at 1,300 °C. Their thermal behavior, crystal structure, morphological characterization, photoluminescence (PL) properties, and excitation mechanism were then investigated.

Experimental

$\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Eu^{3+} and $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Yb^{3+} phosphors were synthesized using the solid-state technique. Starting materials; $4\text{MgCO}_3 \cdot \text{Mg}(\text{OH})_2 \cdot 5\text{H}_2\text{O}$ (A. R.) in triclinic crystal system with lattice parameters $a = 826.16$ pm, $b = 1164.27$ pm, $c = 1742.91$ pm; $\alpha = 144.93^\circ$, $\beta = 47.83^\circ$, $\gamma = 132.09^\circ$, and $V = 684.85 \times 10^6$ pm³, Al_2O_3 (99.0%) compatible with JCPDS file number 75-1864, SiO_2 (99.8%) compatible with JCPDS file number 78-1422, MnO_2 (99.0%) in tetragonal crystal system with lattice parameters $a = 439.57$ pm, $c = 287.30$ pm; and $V = 55.51 \times 10^6$ pm³, Eu_2O_3 (99.99%) compatible with JCPDS file number 12-0393 and Yb_2O_3 (99.99%) compatible with JCPDS file number 06-0371 were weighed according to the nominal compositions of $(\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Eu}_{0.02})\text{Al}_2\text{Si}_2\text{O}_8$ and $(\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Yb}_{0.02})\text{Al}_2\text{Si}_2\text{O}_8$. These powders were mixed homogeneously in an agate mortar for 3 h. Small quantities of H_3BO_3 were added as a flux during the mixing. Its crystal system is triclinic with lattice parameters $a = 492.50$ pm, $b = 1020.50$ pm, $c = 989.82$ pm; $\alpha = 140.51^\circ$, $\beta = 94.55^\circ$, $\gamma = 71.09^\circ$, and $V = 287.00 \times 10^6$ pm³. A small amount of each sample was taken for thermal analysis (DTA/TG) to study the phase-forming process. Thermogravimetry

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(TG) and differential thermal analysis (DTA) were carried out by using a DTA/TG system (Perkin Elmer Diamond type). The samples were heated at a rate of $10\text{ }^{\circ}\text{C min}^{-1}$ from room temperature to $1,300\text{ }^{\circ}\text{C}$, in the nitrogen atmosphere.

Afterwards, the sintering conditions of the phosphors, including the pre-firing temperature and synthesizing temperature, were determined in two steps: first, the mixtures were pre-fired at $900\text{ }^{\circ}\text{C}$ for 3 h in a porcelain crucible in air, and then the pre-fired samples were sintered at $1,300\text{ }^{\circ}\text{C}$ for 3 h in air, in a porcelain crucible. After these procedures the phosphors were obtained and their crystal structures were examined by X-ray diffraction (XRD) analysis using a Bruker AXS D8 Advance diffractometer which was run at 20–60 kV and 6–80 mA, $2\theta = 10\text{--}90^{\circ}$ and a step of 0.002° using $\text{CuK}\alpha$ X-ray.

Scanning electron microscopy (SEM) images and EDX analysis were performed on a LEO 440 model scanning electron microscope using an accelerating voltage of 20 kV.

The decay time, excitation, and emission spectra of the phosphors were recorded by a Perkin Elmer LS 45 model luminescence spectrophotometer with xenon lamp.

Results and discussion

Thermal behavior, crystallization, and morphology

Figure 1 illustrates the DTA/TG curves of nominal composition for $\text{MgAl}_2\text{Si}_2\text{O}_8: \text{Mn}^{4+}, \text{Eu}^{3+}$. The curves below $200\text{ }^{\circ}\text{C}$ include the dehydration of $4\text{MgCO}_3 \cdot \text{Mg}(\text{OH})_2 \cdot 5\text{H}_2\text{O}$ and the decomposition of H_3BO_3 which changes into B_2O_3 . The first endothermic peak is (at $240\text{ }^{\circ}\text{C}$, point A) attributed to the deviation of the hydroxyl group from $\text{Mg}(\text{OH})_2$. The second endothermic peak shows (at $437\text{ }^{\circ}\text{C}$, point B) the decomposition of MgCO_3 which changes into MgO .

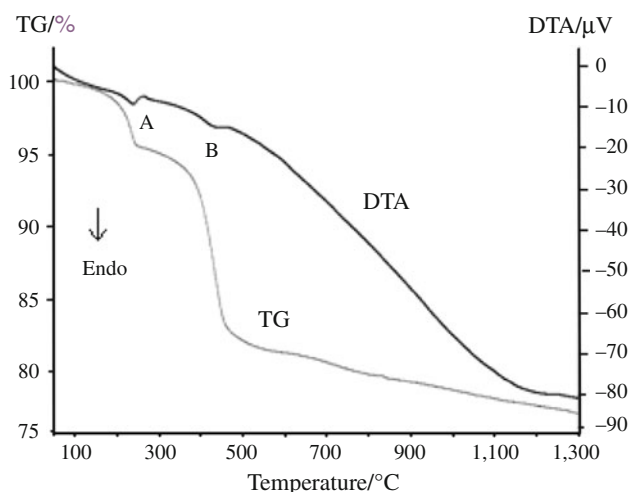


Fig. 1 TG/DTA curves of $\text{MgAl}_2\text{Si}_2\text{O}_8: \text{Mn}^{4+}, \text{Eu}^{3+}$ phosphor

From the above DTA/TG analysis, we carried out the sintering of the phosphors in two steps: first, the samples were pre-fired at $900\text{ }^{\circ}\text{C}$ for 3 h to achieve the dehydration and decomposition of H_3BO_3 , MgCO_3 , and $\text{Mg}(\text{OH})_2$, and to help the doped Mn^{4+} and rare-earth ions to substitute; next the phosphors were prepared at $1,300\text{ }^{\circ}\text{C}$ for 3 h in air. Actually, the crystal systems were not observed at $900\text{ }^{\circ}\text{C}$, but at $1,300\text{ }^{\circ}\text{C}$ for 3 h the $(\text{Mg}_{1-x-y}\text{Mn}_x\text{Eu}_y)\text{Al}_2\text{Si}_2\text{O}_8$ and $(\text{Mg}_{1-x}\text{Mn}_x\text{Yb}_y)\text{Al}_2\text{Si}_2\text{O}_8$ ($x = 0.10$ and $y = 0.02$) non-stoichiometric triclinic crystal systems were observed (Fig. 2).

The XRD patterns of phosphors obtained at 900 and $1,300\text{ }^{\circ}\text{C}$ for 3 h in air are shown in Fig. 2a, b. The unit cell parameters of phosphor crystallized in the triclinic system are listed in Table 1.

Figures 3 and 4 show the images and EDX analysis obtained from the scanning electron microscopy (SEM) of the phosphors calcined at $1,300\text{ }^{\circ}\text{C}$ for 3 h by using solid state reactions. The microstructures of the phosphor consisted of regular fine grains with an average size of about $0.5\text{--}2.7\text{ }\mu\text{m}$.

PL properties

Figure 5 shows the excitation and emission spectra of the $\text{MgAl}_2\text{Si}_2\text{O}_8: \text{Mn}^{4+}, \text{Eu}^{3+}$ phosphor annealed at $1,300\text{ }^{\circ}\text{C}$. The excitation spectrum of the $\text{MgAl}_2\text{Si}_2\text{O}_8: \text{Mn}^{4+}, \text{Eu}^{3+}$ phosphor observed with Mn^{4+} emission at 666 nm (${}^2E \rightarrow {}^4A_2$ transitions) consists of an excitation band with a maximum at 258 nm . Under 258 nm UV excitation, the $\text{MgAl}_2\text{Si}_2\text{O}_8: \text{Mn}^{4+}, \text{Eu}^{3+}$ phosphor shows a strong red luminescence ranging from 600 to 750 nm with a maximum; at 666 nm and some lines ($603, 690,$ and 710 nm) in the longer wavelength region. The red emission at 666 nm , which can be viewed as a typical Mn^{4+} emission, was ascribed to ${}^2E \rightarrow {}^4A_2$ transitions [14]. The emission bands at 603 and 690 nm are due to the transitions of Eu^{3+} ${}^5D_0 \rightarrow {}^7F_2$ and ${}^5D_0 \rightarrow {}^7F_4$, respectively [15, 16]. In order to identify the origin of the emission band of the $\text{MgAl}_2\text{Si}_2\text{O}_8: \text{Mn}^{4+}, \text{Eu}^{3+}$ phosphor at 710 nm , we compared the emission spectrum of the undoped $\text{MgAl}_2\text{Si}_2\text{O}_8$ sample under the same excitation conditions (258 nm). We reported the spectrum of the undoped $\text{MgAl}_2\text{Si}_2\text{O}_8$ in our previous article [17]. It showed an emission ranging from 600 to 800 nm with the three maximum at $617, 710,$ and 720 nm (Fig. 6). The broad $\text{MgAl}_2\text{Si}_2\text{O}_8$ emission band can be attributed to the recombination of an electron and a donor. The recombination was caused by crystal defects which occurred in the undoped $\text{MgAl}_2\text{Si}_2\text{O}_8$ during the solid state process. The emission band at 710 nm in the $\text{MgAl}_2\text{Si}_2\text{O}_8: \text{Mn}^{4+}, \text{Eu}^{3+}$ phosphor has the same profile as that of the undoped $\text{MgAl}_2\text{Si}_2\text{O}_8$ (Fig. 6); thus, it can be ascribed to the host emission.

Fig. 2 XRD patterns of phosphors: **a** ($\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Eu}_{0.02}$) $\text{Al}_2\text{Si}_2\text{O}_8$ and **b** ($\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Yb}_{0.02}$) $\text{Al}_2\text{Si}_2\text{O}_8$

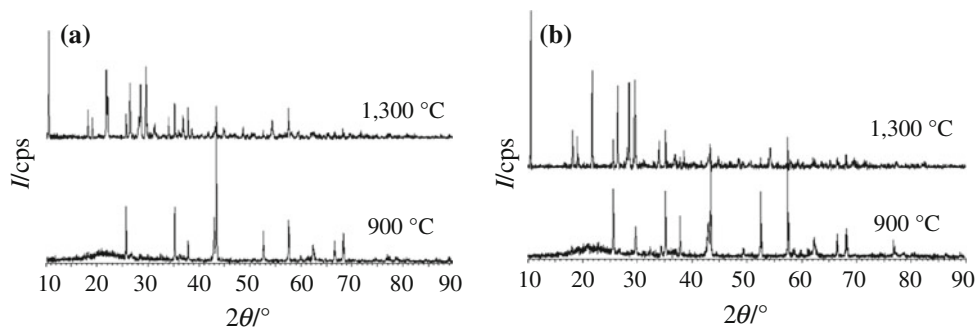


Table 1 Unit cell parameters of phosphors

Phosphor	<i>a</i> /pm	<i>b</i> /pm	<i>c</i> /pm	<i>V</i> × 10 ⁶ pm ³	<i>α</i> /°	<i>β</i> /°	<i>γ</i> /°
($\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Eu}_{0.02}$) $\text{Al}_2\text{Si}_2\text{O}_8$	529.56	944.99	2464.93	1019.72	81.37	67.68	63.36
($\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Yb}_{0.02}$) $\text{Al}_2\text{Si}_2\text{O}_8$	515.59	934.31	1225.48	517.18	75.37	75.67	66.66

Fig. 3 SEM image of: **a** ($\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Eu}_{0.02}$) $\text{Al}_2\text{Si}_2\text{O}_8$ phosphor and **b** ($\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Yb}_{0.02}$) $\text{Al}_2\text{Si}_2\text{O}_8$ phosphor

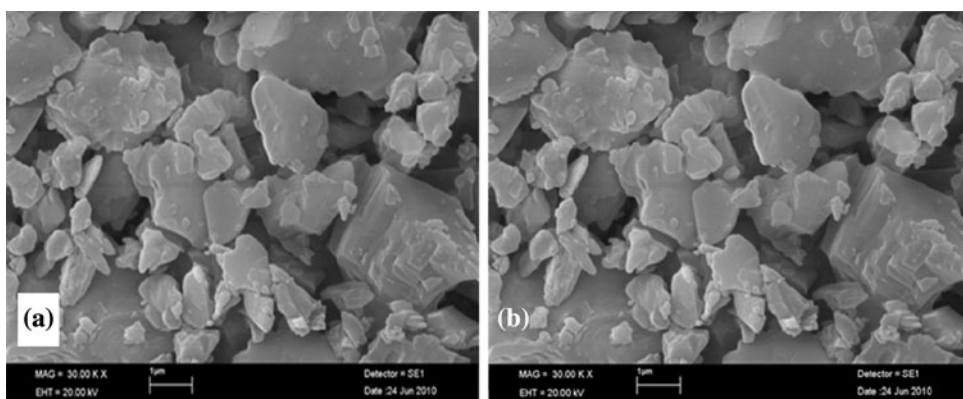
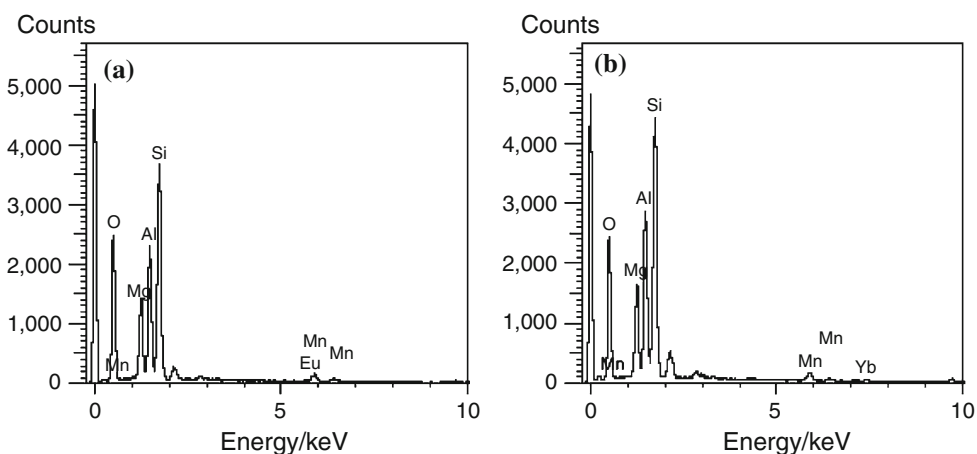


Fig. 4 EDX analysis of: **a** ($\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Eu}_{0.02}$) $\text{Al}_2\text{Si}_2\text{O}_8$ phosphor and **b** ($\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Yb}_{0.02}$) $\text{Al}_2\text{Si}_2\text{O}_8$ phosphor



The excitation and emission spectra of the $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Yb^{3+} phosphor are shown in Fig. 7. Under excitation at 258 nm, the $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Yb^{3+} phosphor exhibits a strong red luminescence. The excitation spectrum of the $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Yb^{3+} phosphor observed with Mn^{4+} emission at 673 nm (${}^2E \rightarrow {}^4A_2$ transitions)

shows a strong excitation band with maximum at 258 nm. When the phosphor was excited at 258 nm, only one emission peak located around 673 nm was observed on the emission spectrum. Such a broad red emission at 673 nm can be viewed as the typical emission of ${}^2E \rightarrow {}^4A_2$ transitions of Mn^{4+} . Typical emission peaks of Yb^{3+} were not

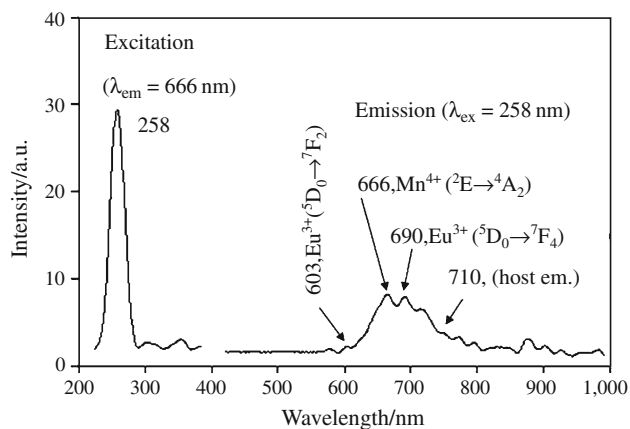


Fig. 5 The excitation and emission spectra of $(\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Eu}_{0.02})\text{Al}_2\text{Si}_2\text{O}_8$ phosphor

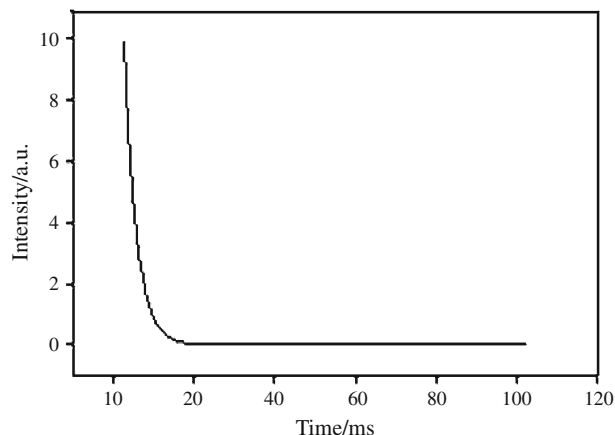


Fig. 8 The decay curves of the $(\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Yb}_{0.02})\text{Al}_2\text{Si}_2\text{O}_8$ phosphors

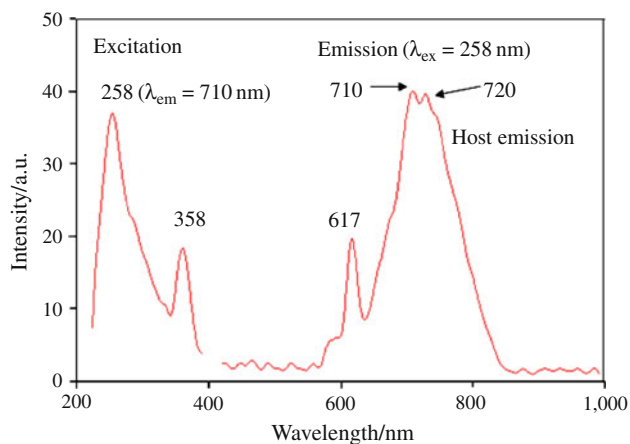


Fig. 6 The excitation and emission spectra of $\text{MgAl}_2\text{Si}_2\text{O}_8$ phosphor

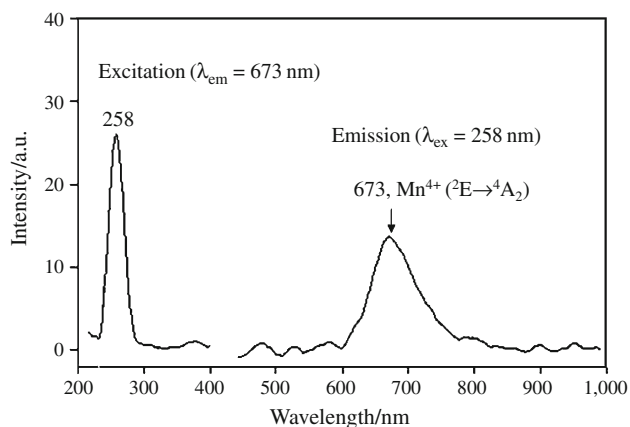


Fig. 7 The excitation and emission spectra of $(\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Yb}_{0.02})\text{Al}_2\text{Si}_2\text{O}_8$ phosphor

observed in the emission spectrum of the $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Yb^{3+} phosphor.

When considering the excitation mechanism, in Figs. 5, 6, and 7, there is only one possible explanation for the excitation bands of the $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Eu^{3+} and $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Yb^{3+} phosphors: this is host crystal absorption. The excitation spectra of the host $\text{MgAl}_2\text{Si}_2\text{O}_8$ (Fig. 6) are in agreement with the excitation spectra of the $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Eu^{3+} (Fig. 5) and $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Yb^{3+} (Fig. 7) phosphors. This indicates that all of the excitation band of the $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Eu^{3+} and $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Yb^{3+} phosphors at 258 nm arise from host lattice absorption. The excitation energy at 258 nm is first captured and then transferred to the Mn^{4+} and Eu^{3+} ions by the host crystal. The presence of the $\text{MgAl}_2\text{Si}_2\text{O}_8$ host crystal's excitation band in the excitation spectra of $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Eu^{3+} and $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Yb^{3+} phosphors shows that an energy transfer takes place from the $\text{MgAl}_2\text{Si}_2\text{O}_8$ host crystal to the Mn^{4+} and Eu^{3+} ions. The excitation energy of the host crystal $\text{MgAl}_2\text{Si}_2\text{O}_8$ doped with Mn^{4+} and Eu^{3+} ions can be non-radiatively transferred to Mn^{4+} and Eu^{3+} ions. As shown in Fig. 7 the energy transfer from the $\text{MgAl}_2\text{Si}_2\text{O}_8$ to Mn^{4+} ions is complete. However, Fig. 5 shows that the emission band at 710 nm from the $\text{MgAl}_2\text{Si}_2\text{O}_8$ host lattice can still be observed in the emission spectrum $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Eu^{3+} . Therefore, the energy transfer from the $\text{MgAl}_2\text{Si}_2\text{O}_8$ host crystal to the Mn^{4+} and Eu^{3+} ions is not complete. In addition, there is no energy transfer from the host crystal $\text{MgAl}_2\text{Si}_2\text{O}_8$ to the Yb^{3+} ions.

The luminescence decay curve of the undoped host crystal $\text{MgAl}_2\text{Si}_2\text{O}_8$: Mn^{4+} , Yb^{3+} phosphor is shown in Fig. 8. Decay time can be calculated by a curve fitting method based on the following single exponential equation:

$$I = A_1 \exp(-t/\tau_1) + C$$

where I is phosphorescence intensity; A_1 , C are constants; t is time; and τ_1 is the lifetime for the exponential components. Decay time (τ_1) for exponential component of $\text{MgAl}_2\text{Si}_2\text{O}_8: \text{Mn}^{4+}, \text{Yb}^{3+}$ phosphor was 3.05 ms. The $\text{MgAl}_2\text{Si}_2\text{O}_8: \text{Mn}^{4+}, \text{Yb}^{3+}$ phosphor shows much longer afterglow than the undoped $\text{MgAl}_2\text{Si}_2\text{O}_8$ phosphor which indicates that Mn^{4+} and Yb^{3+} ions play an important role in prolonging the afterglow.

The decay time of the $\text{MgAl}_2\text{Si}_2\text{O}_8: \text{Mn}^{4+}, \text{Eu}^{3+}$ phosphor cannot be detected and calculated in the same conditions.

Conclusions

In this report, $(\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Eu}_{0.02})\text{Al}_2\text{Si}_2\text{O}_8$ and $(\text{Mg}_{0.88}\text{Mn}_{0.10}\text{Yb}_{0.02})\text{Al}_2\text{Si}_2\text{O}_8$ red phosphors were first prepared by using the solid state reaction at 1,300 °C for 3 h. The phosphors had a triclinic crystal system. Under UV excitation at 258 nm, $\text{MgAl}_2\text{Si}_2\text{O}_8: \text{Mn}^{4+}, \text{Eu}^{3+}$ and $\text{MgAl}_2\text{Si}_2\text{O}_8: \text{Mn}^{4+}, \text{Yb}^{3+}$ phosphors showed strong red luminescence. The mechanism of excitation in $\text{MgAl}_2\text{Si}_2\text{O}_8$ -based phosphors was explained by an energy transfer from the $\text{MgAl}_2\text{Si}_2\text{O}_8$ host crystal to the Mn^{4+} and Eu^{3+} ions.

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